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Standard Recovery Diodes, (Stud Version), 40 A



DO-203AB (DO-5)

PRODUCT SUMMARY				
I _{F(AV)}	40 A			
Package	DO-203AB (DO-5)			
Circuit configuration	Single diode			

FEATURES

- · High surge current capability
- Stud cathode and stud anode version



- · Leaded version available
- Types up to 1600 V V_{RRM}
- Designed and qualified for multiple level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- · Battery charges
- Converters
- Power supplies
- Machine tool controls
- Welding

MAJOR RATINGS AND CHARACTERISTICS					
DADAMETED	TEST COMPLETONS	40F	LINUTO		
PARAMETER	TEST CONDITIONS	10 TO 120	140/160	UNITS	
1		40	40	Α	
I _{F(AV)}	T _C	140	110	°C	
I _{F(RMS)}		62	62	А	
1	50 Hz	570	570	A	
I _{FSM}	60 Hz	595	595		
l ² t	50 Hz	1600	1600	A ² s	
1-1	60 Hz	1450	1450		
V_{RRM}	Range	100 to 1200	1400 to 1600	V	
TJ		-65 to 190	-65 to 160	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$\begin{aligned} I_{RRM} & \text{MAXIMUM} \\ \text{AT T}_{J} &= T_{J} & \text{MAXIMUM} \\ & \text{mA} \end{aligned}$	
	10	100	200		
	20	200	300		
	40	400	500		
	60	600	700	9	
VS-40HF(R)	80	800	900		
	100	1000	1100		
	120	1200	1300		
	140	1400	1500	4.5	
	160	1600	1700	4.5	



FORWARD CONDUCTION							
DADAMETED			TEST CONDITIONS		40HF(R)		
PARAMETER	SYMBOL	TEST CONDITIONS		10 TO 120	140/160	UNITS	
Maximum average forward current at case temperature	I _{F(AV)}	180° condu	ction, half sine w	/ave	40 140	40 110	A °C
Maximum RMS forward current	I _{F(RMS)}		62		2	Α	
		t = 10 ms	No voltage		570		
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		595		_
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		480		A
		t = 8.3 ms	reapplied	Sinusoidal half wave,	500		
	l ² t	t = 10 ms	No voltage	No voltage reapplied initial $T_J = T_J$ maximum	1600		A ² s
Maximum I ² t for fusing		t = 8.3 ms	reapplied		1450		
Maximum From rusing		t = 10 ms	100 % V _{RRM}		11	50	Α3
		t = 8.3 ms	reapplied		1050		
Maximum $I^2\sqrt{t}$ for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied		16 (000	A²√s	
Value of threshold voltage (up to 1200 V)	V _{F(TO)}	$T_J = T_J$ maximum		0.6	35	V	
Value of threshold voltage (for 1400 V/1600 V)	V _{F(TO)}			0.76		76	V
Value of forward slope resistance (up to 1200 V)	r _f	- T _J = T _J maximum		4.2		29	mΩ
Value of forward slope resistance (for 1400 V/1600 V)	r _f			1 _J = 1 _J maximum 3.8		8	1115.2
Maximum forward voltage drop	V_{FM}	$I_{pk} = 125 \text{ A}, T_{J} = 25 \text{ °C}, t_{p} = 400 \mu \text{s rectangular wave}$ 1.30 1.50			1.50	V	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	40H	40HF(R)		
PANAMETER	STWIDOL		10 to 120	140 to 160	UNITS	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-65 to 190	-65 to 160	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	DC operation 0.		12.001	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25		K/W	
N		Not lubricated thread, tighting on nut (1)	3.4 (30)			
Maximum allowable mounting		Lubricated thread, tighting on nut (1)	2.3 (20)		N ⋅ m (lbf ⋅ in)	
torque (+0 %, -10 %)		Not lubricated thread, tighting on hexagon (2)	ated thread, tighting on hexagon (2) 4.2 (37)			
		Lubricated thread, tighting on hexagon (2)	3.2 (28)			
Approximate weight			1	7	g	
Approximate weight			0	.6	OZ.	
Case style		See dimensions - link at the end of datasheet	dimensions - link at the end of datasheet DO-203AB (DO-5)		5)	

Notes

⁽²⁾ Recommended for holed threaded heatsinks

△R _{th} JC CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.14	0.10			
120°	0.16	0.17			
90°	0.21	0.22	$T_J = T_J$ maximum	K/W	
60°	0.30	0.31			
30°	0.50	0.50			

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

⁽¹⁾ Recommended for pass-through holes

Maximum Allowable Case Temperature (°C)

180

170

160

150

140

130

120

0

30 9

10

60

20

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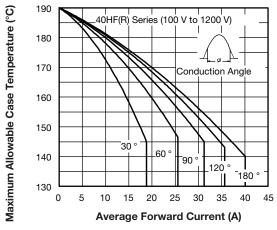


Fig. 1 - Current Ratings Characteristics

40HF(R) Series (100 V to 1200 V)

Conduction Period

180

50

40

DC

60

70



Average Forward Current (A)
Fig. 2 - Current Ratings Characteristics

30

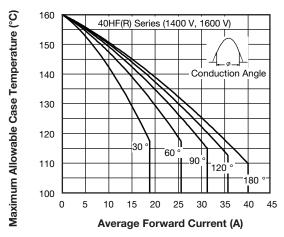


Fig. 3 - Current Ratings Characteristics

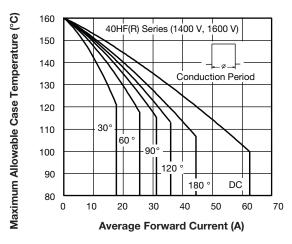


Fig. 4 - Current Ratings Characteristics

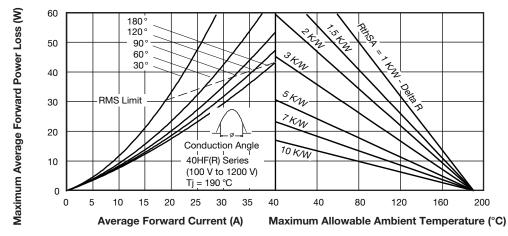


Fig. 5 - Forward Power Loss Characteristics



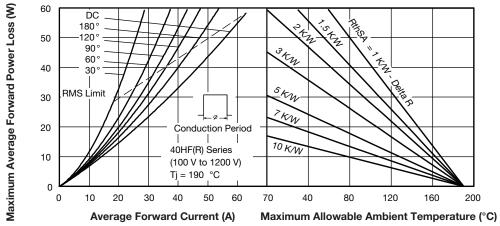


Fig. 6 - Forward Power Loss Characteristics

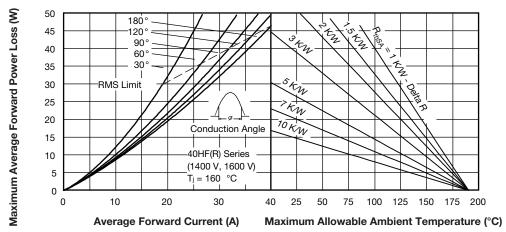


Fig. 7 - Forward Power Loss Characteristics

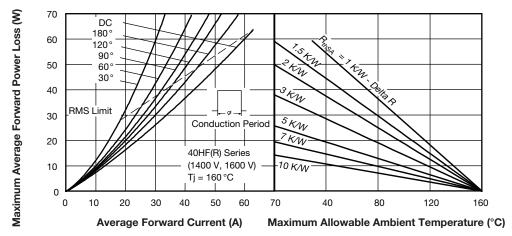


Fig. 8 - Forward Power Loss Characteristics

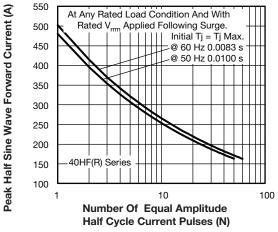


Fig. 9 - Maximum Non-Repetitive Surge Current

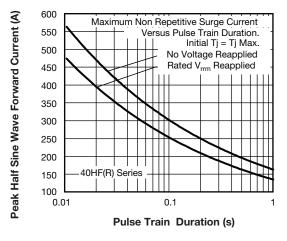


Fig. 10 - Maximum Non-Repetitive Surge Current

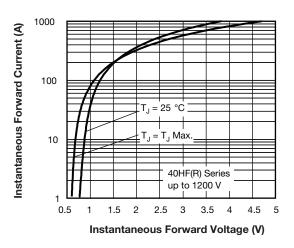


Fig. 11 - Forward Voltage Drop Characteristics (Up To 1200 V)

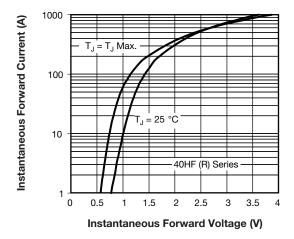


Fig. 12 - Forward Voltage Drop Characteristics (For 1400 V/1600 V)

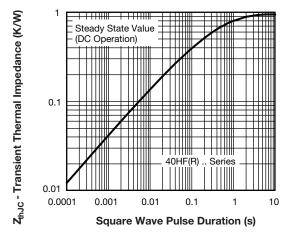
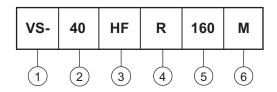


Fig. 13 - Thermal Impedance ZthJC Characteristics

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - • 40 = Standard device

41 = Not isolated lead

• 42 = Isolated lead with silicone sleeve

(red = Reverse polarity)

(blue = Normal polarity)

3 - HF = Standard diode

None = Stud normal polarity (cathode to stud)

• R = Stud reverse polarity (anode to stud)

- Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

- None = Stud base DO-203AB (DO-5) 1/4" 28UNF-2A

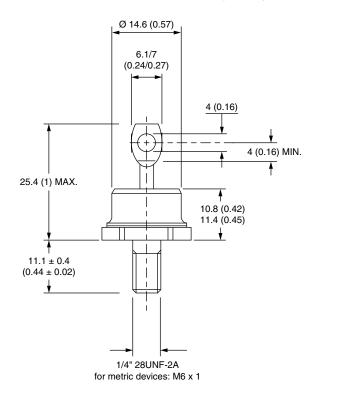
• M = Stud base DO-203AB (DO-5) M6 x 1

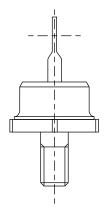
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95344		

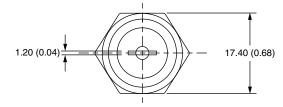


DO-203AB (DO-5) for 40HF(R) and 41HF(R) Series

DIMENSIONS FOR 40HF(R) SERIES in millimeters (inches)







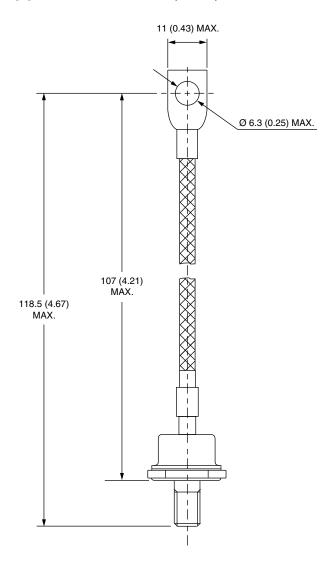
Outline Dimensions

Vishay Semiconductors

DO-203AB (DO-5) for 40HF(R) and 41HF(R) Series



DIMENSIONS FOR 41HF(R) SERIES in millimeters (inches)





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